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		Course Code:	SOE-	B-MA	303
		O P JINDAL UNIVERSITY			Opr
		B. Tech. III Semester Regular Examinations			Urj
D		Engineering Mathematics-III		Ebenasian da S Josephia	ABOX, TXA 24NG MISSIBMBING
	ne: 3	Electrical Engineering Program C			
1 111	ie. 3	Section A : All Questions are compulsory	Max.	Marks:	100
		Section B: Answer any one question from each unit. All questions carry equal ma	rks		
		The second secon	M	CO	K
1200		Section-A		1 10	
	a.	Find $L(e^{-t} \sin 2t)$	2	1	1
1	b.	Find $L^{-1}\left(\log\frac{s+1}{s-1}\right)$	2	1	1
	c.	Round off the number 3.2453 up to three significant figure also find the relative error.	2	2	- 1
	d.	Find the interval to find the root of the equation $x^3 - 30 = 0$ .	2	2	1
	e.	Show that $\mu = \frac{E^{\frac{1}{2}} + E^{-\frac{1}{2}}}{2}$	2	3	1
	f.	Write Simpson's three eight formula.	2	3	1
	g.	Define Picard's method.	2	4	1
	h.	What is Predictor-corrector formula.	2	4	1
	i.	A book has 4 misprint per page on an average, what is the probability that a page will open at random will have no misprint on it.	2	5	2
	j.	If $P(A) = \frac{1}{6}$ , $P(B) = \frac{1}{8}$ , $P(AUB) = \frac{1}{4}$ . Find $P(A/B)$ and $P(B/A)$ .	2	5	2
		Section-B:			
		Unit-I			
	a.	Solve by the method of Laplace transform $(D^3 - 3D^2 + 3D - 1)y = t^2e', y(0) = 1, y'(0) = 0, y''(0) = -2$ .	8	1	3

		OR			
3	a.	Show that $L^{-1}\left(\frac{s}{s^4 + 4a^4}\right) = \frac{1}{2a^2} \sinh at \cdot \sin at$	8	1	3
	b.	Solve by the method of Laplace transform $y'' + y = t$ , $y(0) = y'(0) = 0$ .	8	1	3

Find the Laplace transform of  $f(t) = \begin{cases} \sin 2t, & \pi \le t < 2\pi \end{cases}$ 

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b.

 $\int \sin t, 0 \le t < \pi$ 

 $\sin 3t, t \ge 2\pi$ 

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	a.	0 103 E2						AND THE RESIDENCE OF STREET		Raphson m mpare the r	A STATE OF THE ACT OF THE PARTY	8	2	3
4	b.	app	oroxim	ng Jacob ation $x = 12$ ,	=0, y=0	0, z = 0				g initial	740 7 7	8	2	3
			4147	Bright 100	4 250 2		0	R	topen are		5.00.1989		ووعائلك	inglo in
	a.			following $z = 8, 2x$						ıss Jordan n	nethod.	8	2	3
5	b.	app	roxim	ng Gauss ation <i>x</i> = - 2 <i>z</i> = 17	= 0, y = 0	0, z = 0 :		-		n taking ini	tial	8	2	3
	7			i Mercut	louis of		Unit	-III	10 72 81			30.00		
	a.	foll x:	lowing		ivided d 7 294	10	11		3) and f( 13 2028	11) for the	10 30 30 30	8	3	3
6	b.	Fin	d the		second		1.100			ated below	, at the	8	3	3
			( )	Esylla and	9-4		0	R		kelie internati	A 600 1	neel i		
7	a.			followi ion form 1.7 5.474		1.9 6.686	f(x) wh 2.0 7.389	en x=1.  2.1  8.166	2.2 9.025	2.4 by Ne 2.3 9.974	ewton's	8	3	3
	b.	Eva	aluate	$\int_{0}^{1} \frac{dx}{1+x^2},$	n=10 us	sing Tra	pezoidal	rule and	Simpso	on's one-thi	rd rule.	8	3	3
	200						Unit	t-IV				2.101.1		
8	a.	The second	_	inge Kur $\frac{-x^2}{+x^2}$ , wi			fourth o	The Revenue of the Party of the	d yat .	x = 0.2 and	0.4 for	10	4	3
O	b.		ux	$\frac{y-x}{y+x}$ where modifies				Find an	approx	imate value	of y at	6	4	3
	1						0	R		1 BF 1 Y				

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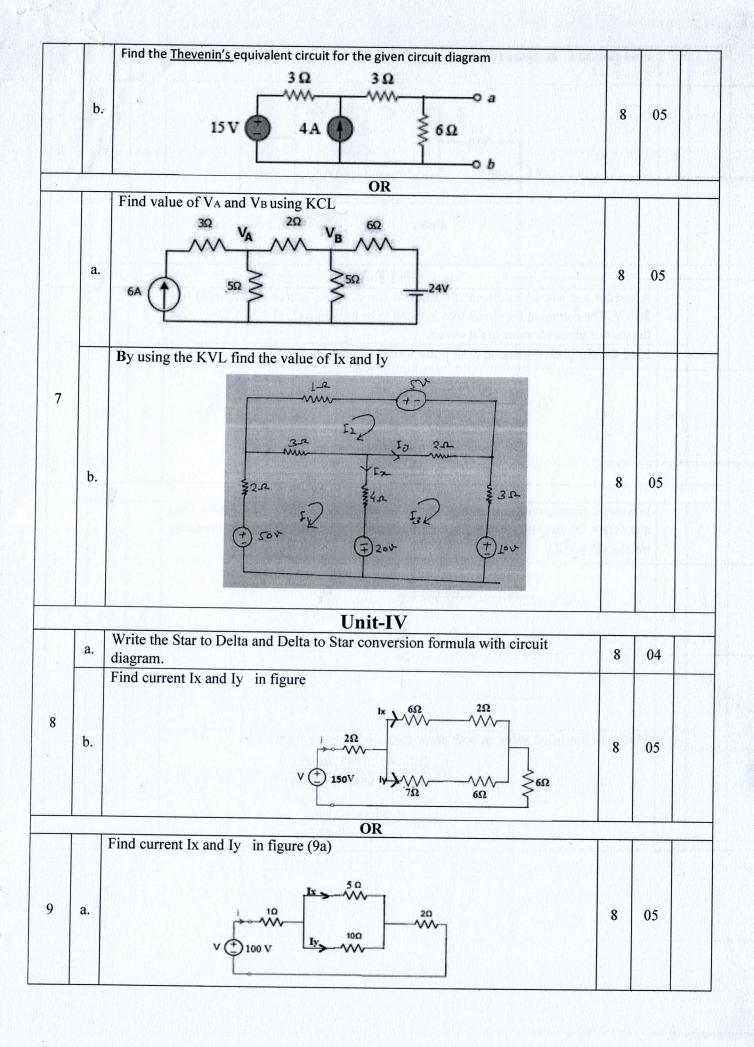
9	a.	Using Adam-Bashforth method, obtain the solution of $\frac{dy}{dx} = x - y^2$ at $x = 0.8$ given $y(0) = 0$ , determine $y(0.2)$ , $y(0.4)$ , $y(0.6)$ by Euler's formula.	10	4	3
9	b.	Using Taylor's series method compute $y(0.1)$ and $y(0.2)$ to three decimal places from $\frac{dy}{dx} = 1 - 2xy$ given that $y(0) = 0$ .	6	4	3
		UNIT-V			
10	a.	If the diameter X(cm) of certain bolt has the density function $f(x) = \begin{cases} k(x-0.9)(1.1-x), 0.9 < x < 1.1\\ 0, otherwise \end{cases}$ . Find $k$ , $\mu$ and $\sigma^2$ .	8	5	3
	b.	If the probability of producing a defective screw P=0.01. What is the probability that a lot of 100 screws will contain more than 4 defectives?	8	5	3
	Digital.	OR			
	a.	Find the mean and variance of the random variable X, where $f(x)$ is the probability function for the uniform distribution [0,10].	8	5	3
11	b.	Five fair coins are tossed simultaneously. Find the probability function of the random variable X=Number of heads and compute the probabilities of obtaining no heads, precisely 1 head, at least 1 head, not more than 4 heads.	8	5	3

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		Course Code: SOE-	D-EE	301	
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	7)			University of 8 and Ma	ETEL TECHNOLOGY N. GEMENT
	Time:	Diploma III Semester Regular Examinations  ELECTRIC CIRCUIT AND NETWORK  Program Code: 01DE060  Time: 3 Hrs.  Section-A  All questions carry equal marks  a. Transformer is which type of element active or passive also write the reaso diagram.  c. Find RaB in the circuit  3Ω 3Ω 6Ω		rks: 10	
			M	CO	KL
		Section-A			
	a.	直接的外域的22 物質 \$45 feet 20 数 10 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	2	03	entard) kairs (f. h
1	b.	Write the Star to Delta and Delta to Star conversion formula with circuit diagram.	2	03	igus.
	c.	$\begin{array}{c c} 3\Omega & 3\Omega \\ \hline  & & \\ \hline $	2	02	
	d.	A LED bulb draws a current of 1 A at 230 V. Find its resistance.	2	04	
	e.	Write the Kirchhoff's current law with diagram.	2	03	1000
	f.		2	04	
	No. of the		2	01	
	n.	↓ ×v <sub>y</sub>	2	01	
	i	Write the Kirchhoff's Voltage law with diagram.	2	03	A STATE OF THE STATE OF
		28 × 18 × 18 × 18 × 18 × 18 × 18 × 18 ×	2	02	
	13.				-
					100
1					
2	a.	If $V1 = 10 \text{ Sin (wt -45 )}$ , $V2 = 20 \text{ Sin (wt -60 )}$ and $V1 = 15 \text{ Sin (wt +30 )}$ Then find (1) $V1 + V2 + V3$ , (2) $V1 - V2 + V3$ ,(3) $V1/V2$ and (4) $(V1 \times V2) \div V3$	8	05	
	b.	Write short notes with diagram on Independent and dependent electric sources.	8	02	
		OR			
	a.	If I1 = 100 Sin (wt +45°), I2 = 10 Sin (wt -450°) and I1 = 150 Sin (wt +30°) Then find (1) I1 + I2+ I3, (2) I1 -I2- I3, (3) I1/I2 and (4) (I1×I2) $\div$ I3	8	05	
3					
3	b.		8	02	

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a.		8	03
	Write down the definition or define the following		
b.	(ii) Power (iii)Thevenin's Theorem (iv)Active and Passive element	8	02
	OR		
	Classified the circuit element on basis of the following groups.		
a.	<ul> <li>(i) Active and Passive</li> <li>(ii) Linear and non-linear</li> <li>(iii) Bilateral and Unilateral</li> <li>(iv) Lumped and distributed</li> </ul>	8	02
	Define Bilateral and Unilateral network and find out which I-V characteristic represent the Unilateral element from the diagrams P,Q, R and S		
b.		8	03
	Unit-III		
	Find the current in 6 $\Omega$ resistor in the circuit shown in Fig. No. (3a) using Mesh analysis (KVL).		
a.	24V T	8	05
	b.	Write down the definition or define the following  (i) Current (ii) Power (iii)Thevenin's Theorem (iv)Active and Passive element  OR  Classified the circuit element on basis of the following groups.  (i) Active and Passive (ii) Linear and non-linear (iii) Bilateral and Unilateral (iv) Lumped and distributed  Define Bilateral and Unilateral network and find out which I-V characteristic represent the Unilateral element from the diagrams P,Q, R and S  b.  P  Unit-III  Find the current in 6 Ω resistor in the circuit shown in Fig. No. (3a) using Mesh analysis (KVL).	a. Write down the definition or define the following  (i) Current (ii) Power (iii) Phevenin's Theorem (iv) Active and Passive element  OR  Classified the circuit element on basis of the following groups.  (i) Active and Passive (ii) Linear and non-linear (iii) Bilateral and Unilateral (iv) Lumped and distributed  Define Bilateral and Unilateral network and find out which I-V characteristic represent the Unilateral element from the diagrams P,Q, R and S  b. P

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## Course Code: SOE-B-EE302

O P JINDAL UNIVERSITY
B. Tech. III Semester Regular Examinations
ELECTRONICS DEVICES AND CIRCUITS



	Time:	(Offered to EE Program Code: 01UG060)  3 Hrs.  Max	Mar	ks: 100	)
		t A is compulsory.			The last
		wer any one question from each unit of Section B			
i	ii) All	questions carry equal marks	Person		
			M	CO	KI
		Section-A			
		What is the relationship between α and β?	2	5	1
	a.	Name the two types of reverse breakdowns which occur in a PN junction		3	1
1	b.	diode?	2	1	1
ilei V	c.	Draw the hybrid model of a BJT.	2	4	1
	d.	What is the need for biasing a transistor?	2	7	2
	e.	What is ripple factor?	2	1	1
	f.	What is I <sub>DSS</sub> in FET?	2	5	2
1	g.	What is the difference between enhancement and depletion type MOSFET?	2	3	2
	h.	Compare the BJT with FET.	2	3	2
	i.	Define pinch-off voltage for a JFET.	2	1	1
	j.	What do you mean by operating point?	2	7	1
		Section-B:			
		Unit-I			
		Why clipper and clamper circuits are used. Draw and discuss different types of	8	7	4
2	a.	clipper and clamper circuits in detail.			
3	b.	Discuss zener diode. How zener diode is used as voltage regulator?	8	2	3
		OR			
		An A.C. voltage of peak value 20 V is connected in series with a silicon diode			
		and load resistance of 500 $\Omega$ . Find: (i) peak current through diode, (ii) peak			
3	a.	output voltage at load.	8	5	3
	Aur a	i) If the forward resistance of diode is $10 \Omega$ , and Cut-in voltage is $0.7 V$ .	Astro-		
		ii) What will be these values if the diode is assumed to be ideal?			
	b.	Draw and discuss in detail the bridge type full wave rectifier.	8	2	2
		Unit-II			
		i) What is meant by base width modulation? How does it affect the working of	Mary 1		
1	a.	transistor?	8	5	4
4		ii) A transistor has an I <sub>C</sub> of 100mA and I <sub>B</sub> of 0.5mA. What is the value of α?	20.00		
	b.	Draw the current components of transistor and also explain any one biasing	8	1	2

a. the state of th	What are different biasing stability factors. For the fixed bias circuit, calculate the all stability factors.  In the circuit, transistor has β =60, V <sub>BE</sub> =0.7V. Find the collector to emitter voltage drop V <sub>CE</sub> .  Unit-III  What is JFET? Discuss in detail with construction, symbol, working and its characteristics.  i) An n-channel JFET has IDSS = 2mA, Vp = -4 V. Find its transconductance gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of  Vds  and iii   large values of  Vds     Vds	8	5 3 5	3 2 3
a. the second of	the all stability factors.  VCC=12V  In the circuit, transistor has β =60, V <sub>BE</sub> =0.7V. Find the collector to emitter voltage drop V <sub>CE</sub> .  Unit-III  What is JFET? Discuss in detail with construction, symbol, working and its characteristics.  i) An n-channel JFET has IDSS = 2mA, Vp = -4 V. Find its transconductance gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of	8 8 8	5	2
5 b. In v. S.	In the circuit, transistor has β =60, V <sub>BE</sub> =0.7V. Find the collector to emitter voltage drop V <sub>CE</sub> .  Unit-III  What is JFET? Discuss in detail with construction, symbol, working and its characteristics.  i) An n-channel JFET has IDSS = 2mA, Vp = -4 V. Find its transconductance gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of	8 8	3	2
b.   In   In   In   In   In   In   In   I	In the circuit, transistor has $\beta$ =60, $V_{BE}$ =0.7V. Find the collector to emitter voltage drop $V_{CE}$ .  Unit-III  What is JFET? Discuss in detail with construction, symbol, working and its characteristics.  i) An n-channel JFET has IDSS = 2mA, $V_{P}$ = - 4 V. Find its transconductance gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of	8 8	3	2
a. Co b. gi i	What is JFET? Discuss in detail with construction, symbol, working and its characteristics.  i) An n-channel JFET has IDSS = 2mA, Vp = - 4 V. Find its transconductance gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of	8		
a. c b. g i b. g i b. g i a. []	What is JFET? Discuss in detail with construction, symbol, working and its characteristics.  i) An n-channel JFET has IDSS = 2mA, Vp = - 4 V. Find its transconductance gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of	8		
a. c b. g i b. g i b. g i a. []	What is JFET? Discuss in detail with construction, symbol, working and its characteristics.  i) An n-channel JFET has IDSS = 2mA, Vp = - 4 V. Find its transconductance gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of	8		
a. c b. g i b. g i b. g i a. []	characteristics.  i) An n-channel JFET has IDSS = 2mA, Vp = - 4 V. Find its transconductance gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values or	8		
b. g i  a. I b. g i  a. I g a.	gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of	8	5	3
b. g i  a. I b. g i  a. I g a.	gm for an applied Vgs of -2 V.  ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values of	8	5	3
a. I b. 3	ii) What is meant by transfer characteristics of JFET?  OR  How does the JFET behave for i) small values of  Vds  and ii) large values or	?		
a. I b. 3	OR  How does the JFET behave for i) small values of  Vds  and ii) large values or	2		
7 a. J. b. 3		r		
7 b. 3		8	7	4
8 a. G	Vds ? Explain with suitable V-I characteristics.			
8 a. I	What are the different types of FET configuration? How does FET	8	6	4
8 a.	configurations are correlated to BJT configuration?			
8 a.	Unit-IV			
8 a.	Discuss depletion type MOSFET in detail with construction, symbol, working	. 8	1	2
	corresponding output and transfer characteristics.	0	1	
	Compare between PMOS and NMOS.	8	3	2
	OR CONTROL OF THE PROPERTY OF			
	Discuss enhancement type MOSFET in detail with construction, symbol	, 8	1	2
a. ,	working. corresponding output and transfer characteristics.			
9	Compare the transfer characteristics of FET, enhancement type MOSFET an	d 8	3	4
b. 6	depletion type MOSFET in detail.			
	UNIT-V	Merica		
	UNII-V	or 8	6	3
10 a.	Determine all the parameters for voltage and current gain and various impedances for	X	0	
b.	Determine all the parameters for voltage and current gain and various impedances for an amplifier circuit using h-parameters.	8	7	2

	a.	Define h-parameters for a BJT in detail.	8	4	2
11	b.	Consider a single state CE amplifier with Rs = $1K\Omega$ and R <sub>L</sub> = $10~K\Omega$ . The h-parameter values are hie = $1.1K$ , hre= $2.5x10^{-4}$ , hfe= $50$ and hoe= $25~\mu$ A/V. Find the various gain and the input and output impedances.		5	3

		Course Code: SC	E-B-E	E303	
		O P JINDAL UNIVERSITY			
		B. Tech. III Semester Regular Examinations		R	20
		B. Tech. III Semester Regular Examinations  Electrical Machine-I Offered to EE (01UG060)  me: 3 Hrs.  Answer any one question from each unit All questions carry equal marks  Section-A  a. What is the function of compensating winding? b. Explain the law of conservation and give some examples. c. Why transformer rating is expressed in terms of kVA? d. Define all day efficiency of a transformer. e. What are the necessary conditions required for the parallel operation of a single-phase transformer? f. What is the condition of maximum efficiency of the transformer g. What is the use of inter pole in the d.c. machine? h. What is the condition of maximum efficiency of d.c. shunt generator. i. Explain the Back EMF of d.c. motor  Section-B: Unit-I  a. What are the types of d.c. machines? explain in detail. b. Explain in detailed construction of d.c. generator.  OR  a. What is the difference between Lap winding and wave winding? b. Explain in detail the construction and operation of d.c. generator.  Unit-II a. What is the principle of a single-phase transformer? Derive their e.m.f equation. A 25 kVA transformer has 500 turns on of the primary and 50 turns on the secondary winding the primary is connected to a 3000-V,50-Hz supply. Find the full load current of primary and secondary current, the secondary e.m.f. and the maximum flux in the core Neglect leakage drop and no-load primary current.			
	l'ime:	是一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个	Max. M	arks: 1	00
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		An questions carry equal marks	M	CO	KL
		Section A	TVA	1 00	171
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		一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是一个人,我们就是	2	2	2
		是一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个一个			27 - 34
1	and the second section	phase transformer?	2	3	2
	f.	What is the condition of maximum efficiency of the transformer	2	3	4
	g.	What is the use of inter pole in the d.c. machine?	2	4	4
	AND DESCRIPTION OF THE PARTY NAMED IN		2	4	3
	i.		2	5	1
415	j.	Why a starter is necessary for a DC motor?	2	5	1
	2.00	Section-B:	VI.AT		
	а		8	111	4
2		The second of th	8	1	4
	10.		•	The state of the s	
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3	- Indiana		8	1	4
	b.	A CONTROL OF THE PARTY OF THE P	8	1.1	4
	1.754	Unit-II			
	a.		8	2	4
	1				
4	L	secondary winding the primary is connected to a 3000-V,50-Hz supply. Find the	0		
	0.		8	2	5
		maximum flux in the core Neglect leakage drop and no-load primary current.			
	. 1773			recombined to the con-	
	2	Draw the phasor diagram of the transformer with winding resistance but no	8	2	4
	a.		- 0		4
5		。	1 . 17	3 3 3 3 3	
•	b.		8	2	5
	-		3	- 1.00000 - 1.00000	J
	1 1	reactance and impedance referred to the (i) High voltage side (ii) low voltage side.		The same	

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6	a.	Explain the different connection diagrams of 3 phase transformer.	8	3	3
0	b.	Explain the working of single-phase auto-transformers with neat diagrams.	8	3	3
		OR			
7	a.	What are the condition of the parallel operation of 3 phase transformer?	8	3	3
1	b.	Explain the Scott connection of the transformer.	8	3	3
		Unit-IV			
The same	a.	Derived the EMF equation of d.c. generator? explain in detail.	8	4	3
8	b.	A long shunt compound generator delivers a load current of 50 Amp at 500 V and has armature, series field and shunt field resistance of $0.05 \Omega$ , $0.03 \Omega$ and $250 \Omega$ respectively. Calculate the generated voltage and armature current. Allow 1 volt per brush for contact drop.	8	4	3
		OR			
	a.	What do you understand about the armature reaction explain in detail? Describe the role of compensating windings in a dc generator.	8	4	3
9	b.	A 4-pole, long-shunt lap-wound generator supplies 25 kW at a terminal voltage of 500V. The armature resistance is 0.03 $\Omega$ , the series field resistance is 0.04 $\Omega$ and the shunt field resistance is 200 $\Omega$ . The brush drop may be taken as 1.0 volt Determine the e.m.f. generated. Calculated also no of conductors if the speed is 1200 r.p.m. and flux per pole is 0.02 weber. Neglect armature reaction.	8	4	3
		UNIT-V	. Š. 4		
	a.	Explain the method of speed control of d.c. series and shunt motor.	8	5	5
10	<b>b.</b>	A 4 pole 240 V, wave connected shunt motor 11190 kW, when running at 1000 r.p.m. and armature and field resistance of 50 Amp and 1.0 Amp respectively. It has 540 conductors. Its resistance has 0.1 $\Omega$ . Assuming 1 volt per brush. Find the (i) Armature Torque, (ii) Shaft torque, (iii) Useful flux /pole, and (iv) efficiency.	8	5	5
1.1.0		OR			
	a.	Draw the characteristics of series and shunt motor and explain it in detail.	8	5	5
11	b.	A 230 V d.c. shunt motor has an armature resistance of 0.5 ohm and field resistance of 115 $\Omega$ . At no load, the speed is 1200 r.p.m. and the armature current 2.5 A. On the application of rated load the speed drop to 1,120 r.p.m. Determine the line current and power input when the motor delivers the rated load.	8	5	5

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MU SWEET - 11		O P JINDAL UNIVERSITY	Section 1		
B. Tech. III Semester Regular Examinations			R 20		20
		Electrical Machine-I	79,50		
,	D:	Offered to EE (01UG060)			
	ı ıme:		Max. M	arks: 1	00
	-	Answer any one question from each unit  All questions carry equal marks			
		An questions carry equal marks	M	СО	KI
		Section-A	7. 300000	100	
	a.	What is the function of compensating winding?	2	1 1	3
	b.	Explain the law of conservation and give some examples.	2	1	3
	c.	Why transformer rating is expressed in terms of kVA?	2	2	1
	d.	Define all day efficiency of a transformer.	2	2	2
1	e.	What are the necessary conditions required for the parallel operation of a single-phase transformer?	2	3	2
	f.	What is the condition of maximum efficiency of the transformer	2	3	4
	g.	What is the use of inter pole in the d.c. machine?	2	4	4
	h.	What is the condition of maximum efficiency of d.c. shunt generator.	2	4	3
	i.	Explain the Back EMF of d.c. motor	2	5	1
	i.	Why a starter is necessary for a DC motor?	2	5	1
		Section-B:	(143-7)	kriisti il	144
		Turit-Interest in			
	a.	What are the types of d.c. machines? explain in detail.	8	1 1 1 1	4
2	b.	Explain in detailed construction of d.c. generator.	8	1	4
	10.		0	1	10.000000000000000000000000000000000000
		OR			
3	a.	What is the difference between Lap winding and wave winding?	8	1 1	4
	b.	Explain in detail the construction and operation of d.c. generator.	8	1 - 1	4
	The second	The state of the processory conditions region Unit-Haussier of the state of a substitution of		Jasan	
	a.	What is the principle of a single-phase transformer? Derive their e.m.f equation.	8	2	4
4	b.	A 25 kVA transformer has 500 turns on of the primary and 50 turns on the secondary winding the primary is connected to a 3000-V,50-Hz supply. Find the full load current of primary and secondary current, the secondary e.m.f. and the maximum flux in the core Neglect leakage drop and no-load primary current.	<b>8</b>	2	5
		OR	September 1981		
5	a.	Draw the phasor diagram of the transformer with winding resistance but no leakage reactance.	8	2	4
	b.	A 30 KVA, 2400/120V, 50-Hz transformer has a high voltage winding resistance of 0.1 $\Omega$ and a leakage reactance of 0.22 $\Omega$ . The low voltage winding resistance is 0.035 $\Omega$ and the leakage reactance is 0.012 $\Omega$ . Find the equivalent resistance reactance and impedance referred to the (i) High voltage side (ii) low voltage side.	8	2	5

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and used correct of primary that secondary current, the secondary current and the

to a wind phases, diagrams of the transformer with willing resistance but no

	a.	Explain the different connection diagrams of 3 phase transformer.	8	3	3
6	b.	Explain the working of single-phase auto-transformers with neat diagrams.	8	3	3
	7	OR			de topo.
_	a.	What are the condition of the parallel operation of 3 phase transformer?	8	3	3
7	b.	Explain the Scott connection of the transformer.	8	3	3
		Unit-IV			
	a.	Derived the EMF equation of d.c. generator? explain in detail.	8	4	3
8	b.	A long shunt compound generator delivers a load current of 50 Amp at 500 V and has armature, series field and shunt field resistance of $0.05 \Omega$ , $0.03 \Omega$ and $250 \Omega$ respectively. Calculate the generated voltage and armature current. Allow 1 volt per brush for contact drop.	8	4	3
	Lagrania.	OR			
	a.	What do you understand about the armature reaction explain in detail? Describe the role of compensating windings in a dc generator.	8	4	3
		A 4-pole, long-shunt lap-wound generator supplies 25 kW at a terminal voltage of			
9	es es entiga	500V. The armature resistance is 0.03 $\Omega$ , the series field resistance is 0.04 $\Omega$ and	1.80		
	b.	the shunt field resistance is 200 $\Omega$ . The brush drop may be taken as 1.0 volt Determine the e.m.f. generated. Calculated also no of conductors if the speed is	8	4	3
		1200 r.p.m. and flux per pole is 0.02 weber. Neglect armature reaction.	10		
		UNIT-V			
	a.	Explain the method of speed control of d.c. series and shunt motor.	8	5	5
		A 4 pole 240 V, wave connected shunt motor 11190 kW, when running at 1000	8	1	
10	b.	r.p.m. and armature and field resistance of 50 Amp and 1.0 Amp respectively. It has 540 conductors. Its resistance has $0.1 \Omega$ . Assuming 1 volt per brush. Find the	8	5	5
		(i) Armature Torque, (ii) Shaft torque, (iii) Useful flux /pole, and (iv) efficiency.	40		
		OR			
11 .	a.	Draw the characteristics of series and shunt motor and explain it in detail.	8	5	
	b.	A 230 V d.c. shunt motor has an armature resistance of 0.5 ohm and field resistance of 115 $\Omega$ . At no load, the speed is 1200 r.p.m. and the armature current 2.5 A. On the application of rated load the speed drop to 1,120 r.p.m. Determine the line current and power input when the motor delivers the rated load.	8	5	

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the control to be well argue when the meter delivers and rated look

-		Course Code: SO	E-B-	LE-304	
		O P JINDAL UNIVERSITY		Ser.	OPIL
	B. Tech. III Semester Regular Examinations				
	-	Data Structure & Algorithms Program Code: 01UG020		ASDAD	MEE TECHNOLO SMANIEST
	Time:		Aoy I	Marks: 1	00
		y one question from each unit	14X. 1	viai ks. i	.00
All (	questic	ons carry equal marks.			
			M	CO	KI
		* Section-A			
1	a.	Write the definition of Data Structure.	2	CO1	K
1	b.	What is an algorithm.	2	CO1	K
	c.	Write down the types of data structure.	2	CO1	K
-	d.	Define stack data structure.	2	CO2	K
	e.	What are the applications of queue data structure?	2	CO3	K
	f.	Write the advantages of linked list data structure.	2	CO3	K
	g.	What are the basic operations associated with data structure?	2	CO1	K
	h.	Define tree data structure with advantages.	2	CO4	K
	i.	What are the applications of graph data structure?	2	CO4	K
	j.	Define binary search tree.	2	CO5	K
	a.	Explain the criterion of algorithm analysis.	8	CO1	K3
_	1	Fundain have a single state of the state of		COI	
2	b.	Explain how an infix expression can be converted to a post fix expression with an example.	8	CO1	K3
		OR			
3	a.	How to represent Queue using array. Write algorithm for enque and deque operation.	8	CO1	K3
	b.	What is a graph? Explain how graphs are represented.	8	CO1	K3
		Unit-II			
4	a.	Explain double ended queue with help of example.	8	CO2	K3
	b.	What is stack? Write algorithm for performing basic operations on stack, if its implemented using array.	8	CO2	K3
		OR			
	1	(b) Write a brief note on Traversing a binary tree. Find the preorder and	8	CO2	K3

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		(2) (7) (8)			
		3 6 9 12			
		4 5 10 11		2010 DI	
	b.	What is linked list? How is it represented in memory? Briefly explain header linked list.	8	CO2	K3
		Unit-III	eh w	in III	
	a.	Write down the algorithm for insertion of an element inside the linked list.	8	CO3	К3
6	b.	Explain sequential and linked representation of binary tree with help of example.	8	CO3	K3
		OR		and t	1
7	a.	Explain and implement a single linked list with an example.	8	CO3	K3
	b.	What is a priority queue? Implement using a linked list.	8	CO3	K3
		Unit-IV		The second second section of the second	
8	a.	What is a spanning tree? Explain how minimal spanning trees are constructed with an example.	8	CO4	К3
	b.	Explain a Binary Search Tree (BST) with an example.	8	CO4	K3
		OR OR	i din	har A	
9	a.	Explain quick sort algorithm with suitable example.	8	CO4	K3
9	b.	Write down the bubble sort algorithm and explain.	8	CO4	K3
		UNIT-V			
10	a.	Explain in details tree traversal techniques.	8	CO5	K3
10	b.	Write down the traversal techniques of graph with example.	8	CO5	K3
		OR			
11	a.	Explain binary search algorithm by suitable example. Discuss the complexity of Binary search algorithm.	8	CO5	K3
	b.	Write an algorithm for DFS graph traversal.	8	CO5	K3

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### Course Code: SOE-B-CE305 O P JINDAL UNIVERSITY OPIU **B. Tech. III Semester Regular Examinations** Disaster Management (Online) (Offered to CE, ME, EE) Time: 02 Hrs. Max. Marks: 50 Answer any one question from each unit All questions carry equal marks M CO KL Unit-I (10 marks) Define the term 'Disaster'? 2 I 1 b. Summarize the various types of floods? 8 1 II OR Summarize the various types of droughts? 2 a. 5 1 II What are the various causes of forest fires? b. 5 1 I Unit-II (10 marks) Write down the process of EIA? II 3 What are the shortcomings of EIA? b. 4 2 II OR What are the major elements of land-use planning? a. 2 I Write a short note on "Traditional Disaster Resistant Construction 4 b. 4 II Techniques"? Unit-III (10 marks) Write down the methods to mitigate the impact of the Tsunami? 5 3 II 5 b. Briefly illustrate various methods to mitigate the impact of cyclones? 5 3 II OR Briefly describe various methods to mitigate the damage due to Earthquake? a. 5 3 II 6 What are the various causes of Epidemics? 5 3 I Unit-IV (10 marks) 7 a. Draw Disaster management cycle and briefly describe each term? 10 4 II OR Summarize the phases, focus, objectives and distinctive features of Community 8 a. 10 II Based Disaster Management (CBDM)? UNIT-V (10 marks) What is NDRF and its role in case of disasters? a. 5 5 9 What are the other activities beside search and rescue operations undertaken b. 5 5 I during emergency situation in which NDRF is engaged? What are the immediate and long-term response of (i) Cyclone & (ii) Drought? 10 10

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Course Code: SOE-B-CSE303

## O P JINDAL UNIVERSITY

# B. Tech. III Semester Regular Examinations OPERATING SYSTEM



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	7	(Offered to CE, ECE EEE & ME)			
			Iax. N	Iarks: 1	00
M		Answer any one question from each unit			,
		All questions carry equal marks			
			M	CO	KL
	1 8	Define Operating Systems and discuss its role from different perspectives.			
1	-	Write short note on CPU scheduling criteria.	10	CO	KL
			10	CO2	KL:
	a	List out different services of Operating Systems and explain each service.			
2		Explain different types of CDLI Salada La Salada Explain each service.	10	COI	KLI
	b	Explain different types of CPU Schedulers. i) Preemptive and non-preemptive scheduling ii) I/O bound and CPU bound iii) Scheduler and dispatcher	10	603	
			10	CO3	KL2
	1	Distinguish C. H.	1		
	a	Distinguish among following terminologies i) Multiprogramming systems ii)		T	1.
	-	Wultidaking Systems III) Multiprocessor systems	10	CO2	KLI
3		What is the difference between a preemptive and non-preemptive scheduling algorithm?			
	b.	Explain 1 C13 scileduling algorithm. Find the average turnground time and			
		waiting time for the processes given in the table below. Process CPI burst time (in ma)	10	CO3	KL3
		P1: 24, P2: 3, P3: 3.			
	1	What is distributed and in		1	1
	a.	What is distributed operating system? What are the advantages of distributed operating system?			
4		System.	10	CO4	KL3
	b.	Explain the concept of 'process'. also describe the contents of a process control block (PCB).			
		(1  CB).	10	CO <sub>3</sub>	KL2
	10	What are a Unit-III		1	-
5	a.	What are system calls? Explain different categories of system calls with example?	10	COL	KL3
200	b.	Describe necessary conditions for a deadlock situation to arise.	10	CO2	KL2
	1	OR		1_002	I KLZ
6	a.	Explain the distinguishing features of i). Real time system ii) Multiprocessor system.	10	CO4	KL2
	b.	Explain the methods for deadlock prevention.	10	CO2	KL2
		Unit-IV		002	IXLZ
7	a.	What is operating system? What are functions of operating system?	10	CO2	VI 1
	b.	What is deadlock? Explain the necessary conditions for its occurrence.	10	CO3	KL1
		OP	10	CO2	KL1
3	a.	What do you mean by PCB? Where is it used? What are its contents?	10	COI	VI 1
	b.	What is fragmentation? Explain its types and disadvantages	10	CO1	KL1
		IINIT-V	10	COI	KL1
	a.	What is a process? Draw and explain process state diagram	10	602	1/1
9	b.	Differentiate between the following a) Paging and Segmentation b) Page table and	10	CO3	KLI
	0.	segment table.	10	CO3	KL2
		OR			
	a.	Explain three requirements that a solution to critical section problem must satisfy	10	COA	1/1.2
	b.	explain paging scheme of memory management. What hardware support is product for	10	CO4	KL2
		its implementation?	THE RESIDENCE	TO STORY OF STREET	

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